

Electronic Supplementary Material (ESI)

Mo₂C-induced solid-phase synthesis of ultrathin MoS₂ nanosheet arrays on bagasse-derived porous carbon frameworks for high-energy hybrid sodium-ion capacitors

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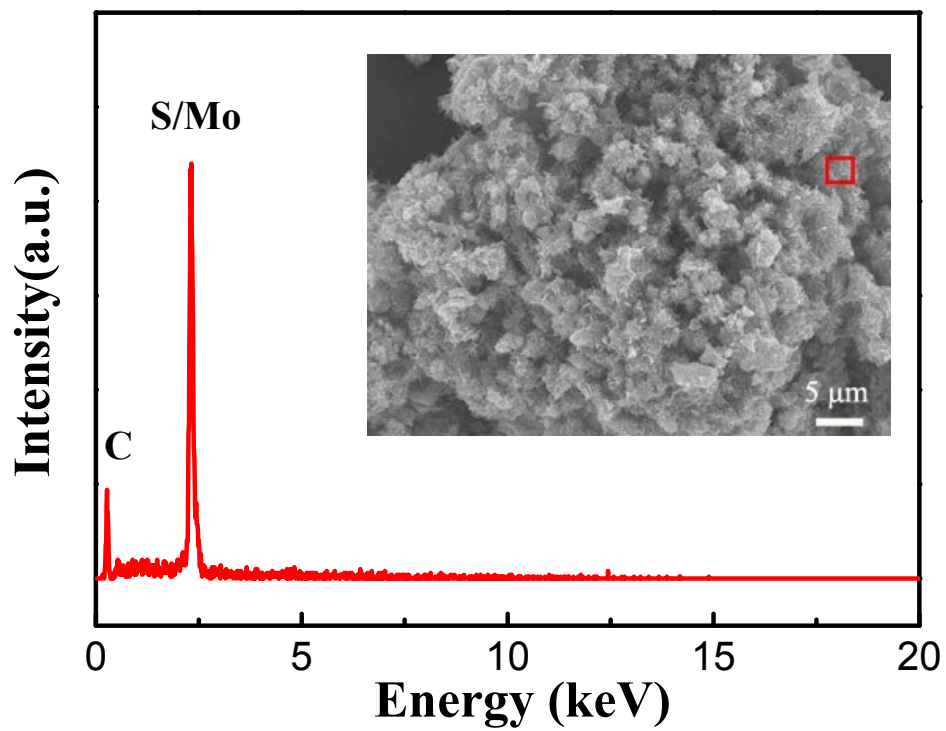


Fig. S1 EDX spectrum of the MoS_2 @bagasse-derived porous carbon (BPC) obtained by SEM-EDX analysis.

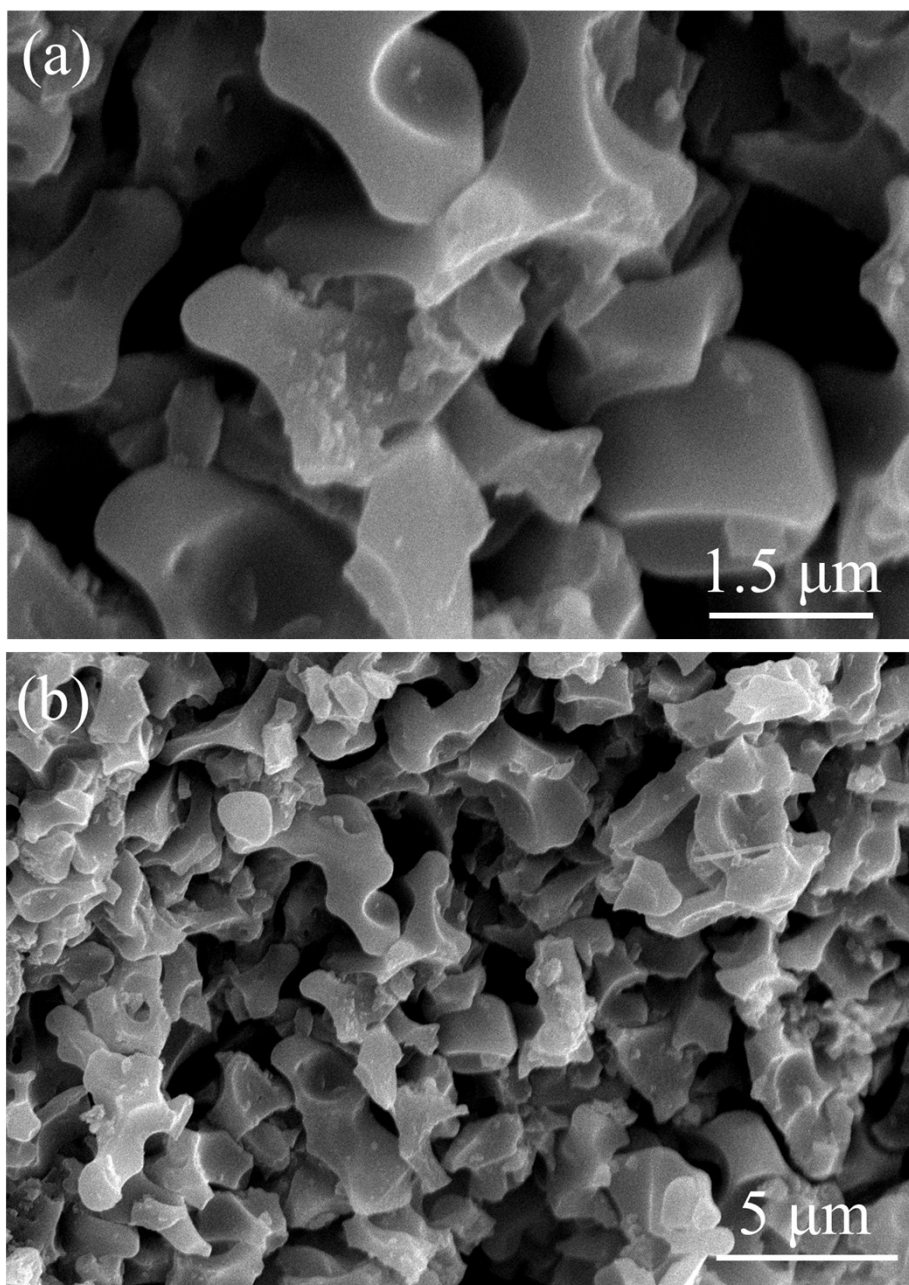


Fig. S2 SEM images of “MoS₂+BPC”. The product was prepared by one-step sulfuration of the “BPC+S+(NH₄)₆Mo₇O₂₄·4H₂O” mixture.

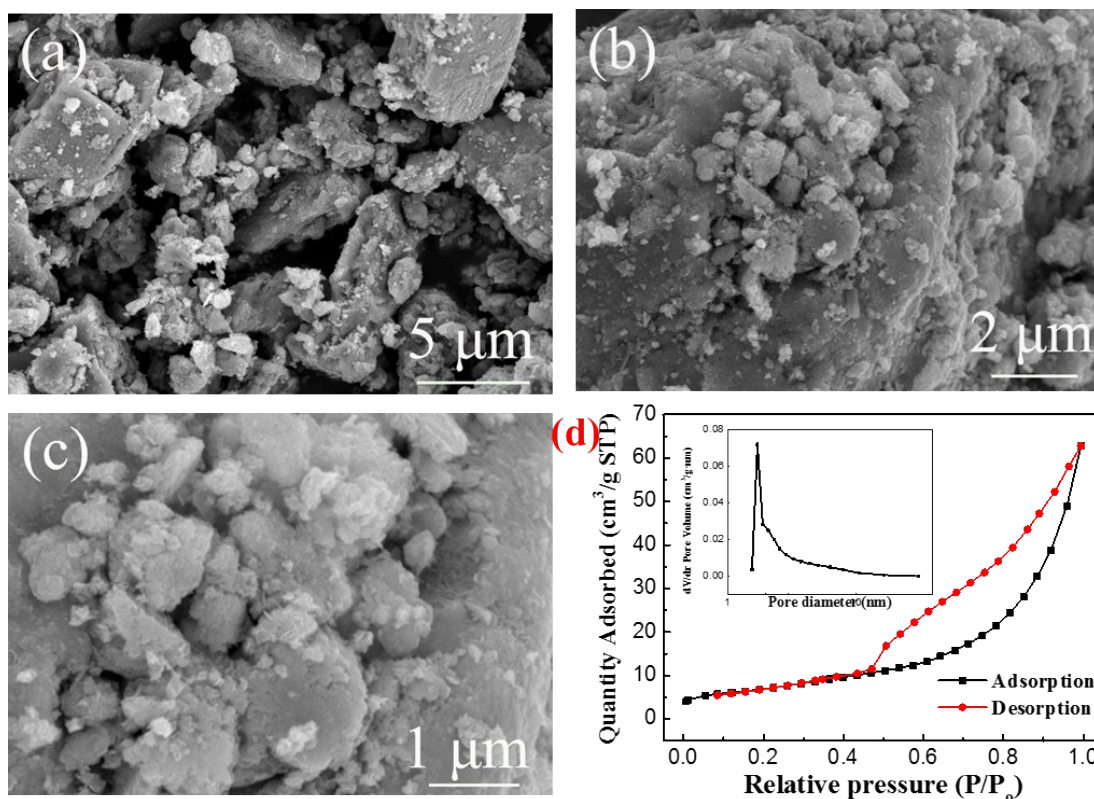


Fig. S3 (a-c) FESEM images and (d) N₂ adsorption-desorption isotherms and porosity distribution of pure MoS₂ sample, which was obtained by annealing the “sulfur + (NH₄)₆Mo₇O₂₄·4H₂O” mixture.

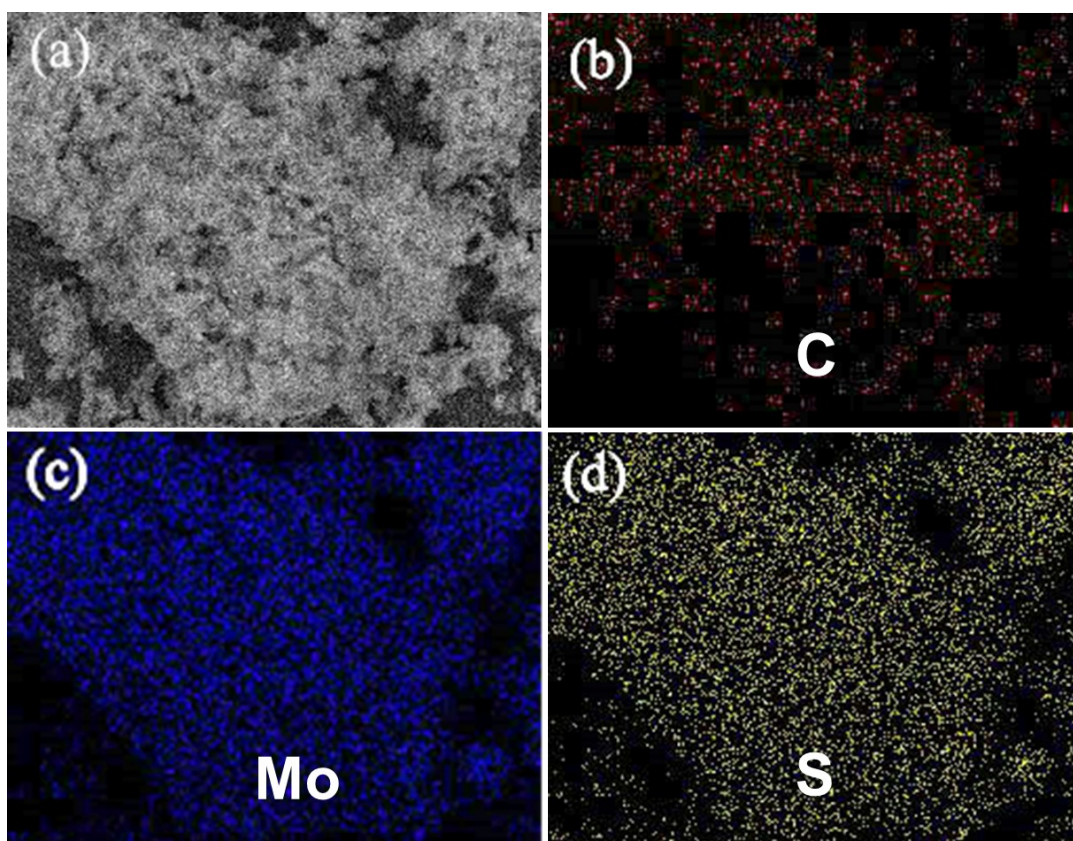


Fig. S4 Morphologies (a) of the MoS₂@BPC composite. (b-d) elemental mapping images of b) C, c) Mo, and d) S.

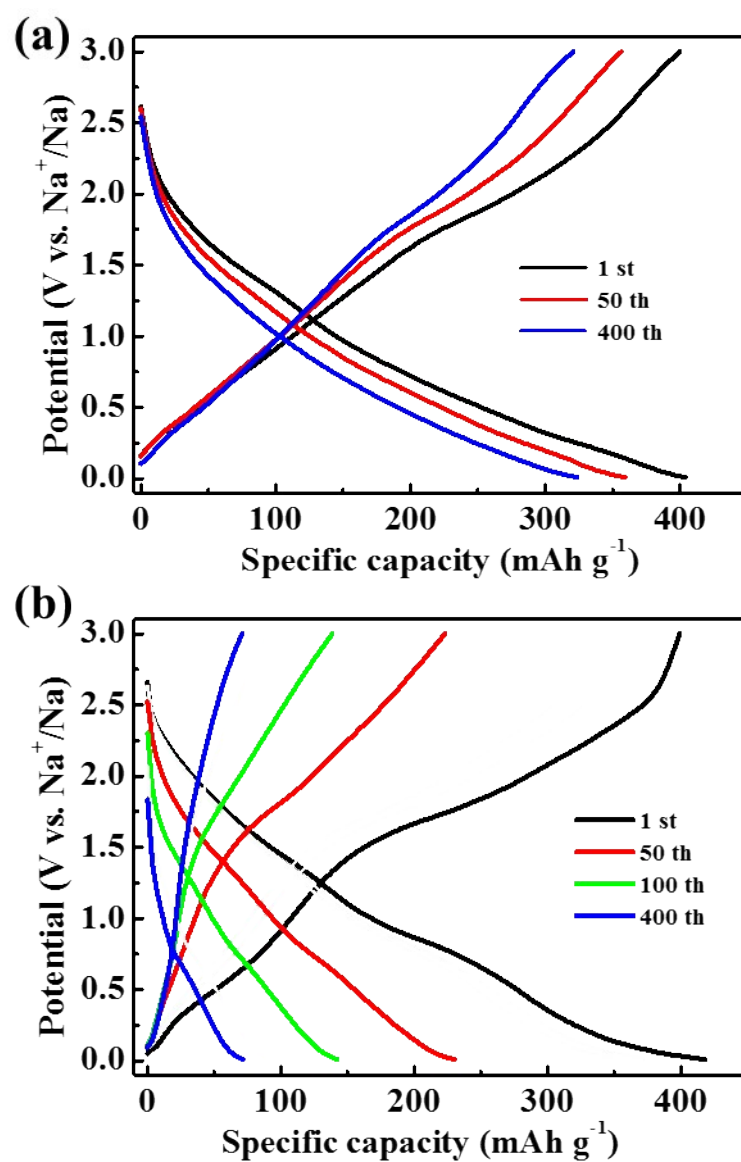


Fig. S5 GCD curves of MoS₂@BPC (a) and pure MoS₂ (b) at 0.2 Ag⁻¹.

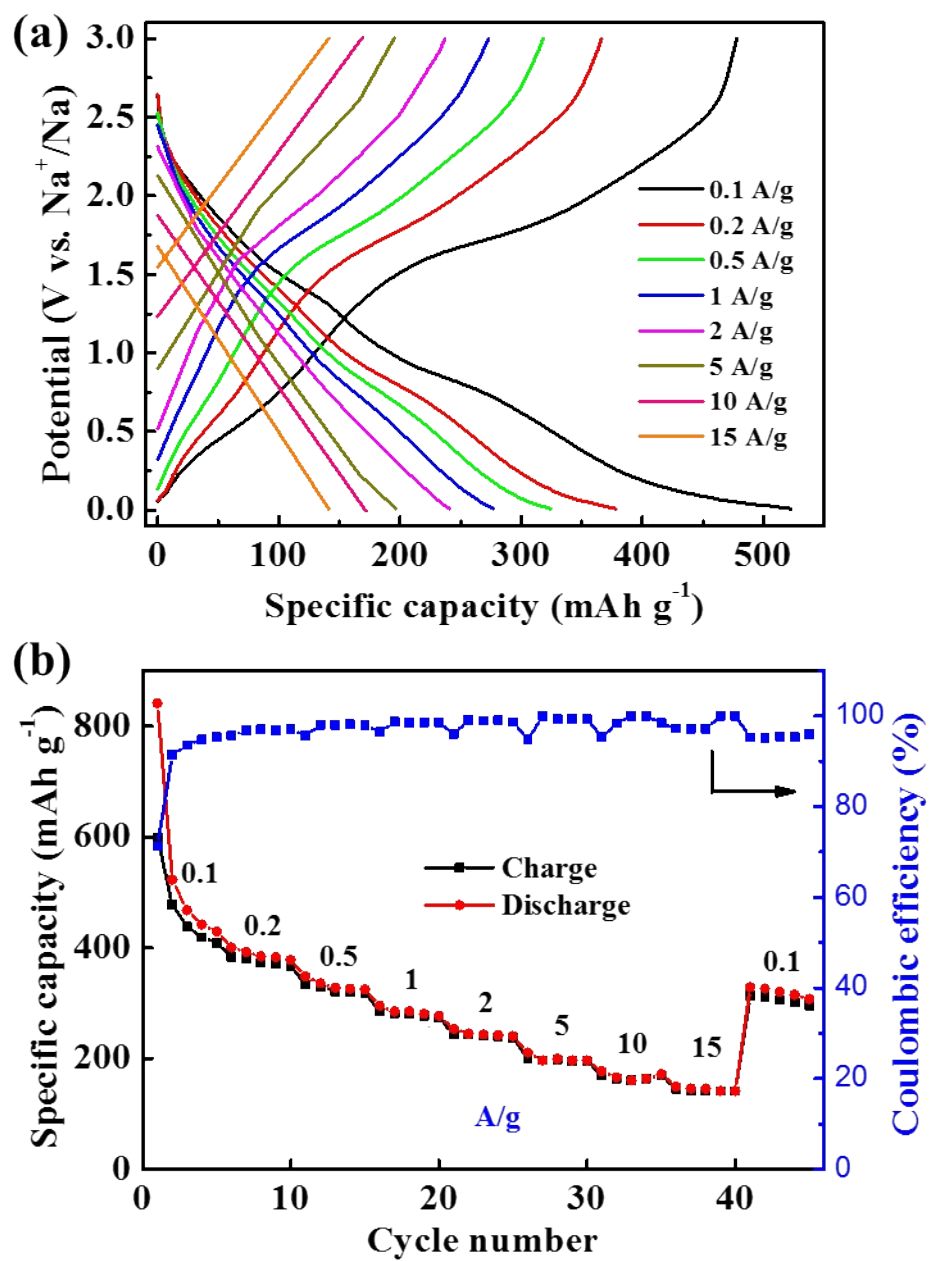


Fig. S6 (a) GCD curves and (b) Rate performance of the pure MoS₂ electrode.

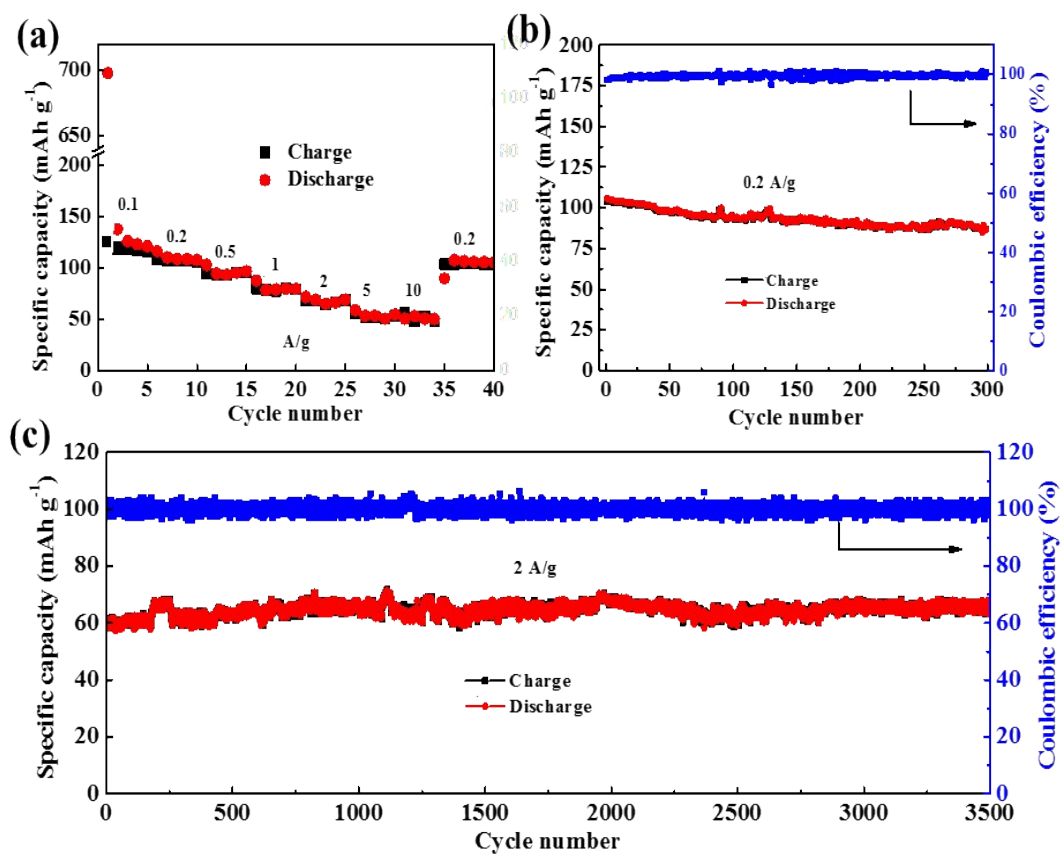


Fig. S7 (a) Rate performance and cycling performance at (b) 0.2 A g⁻¹ and (c) 2 A g⁻¹ of the BPC electrode in the range of 0.01–3 V (vs Na/Na⁺).

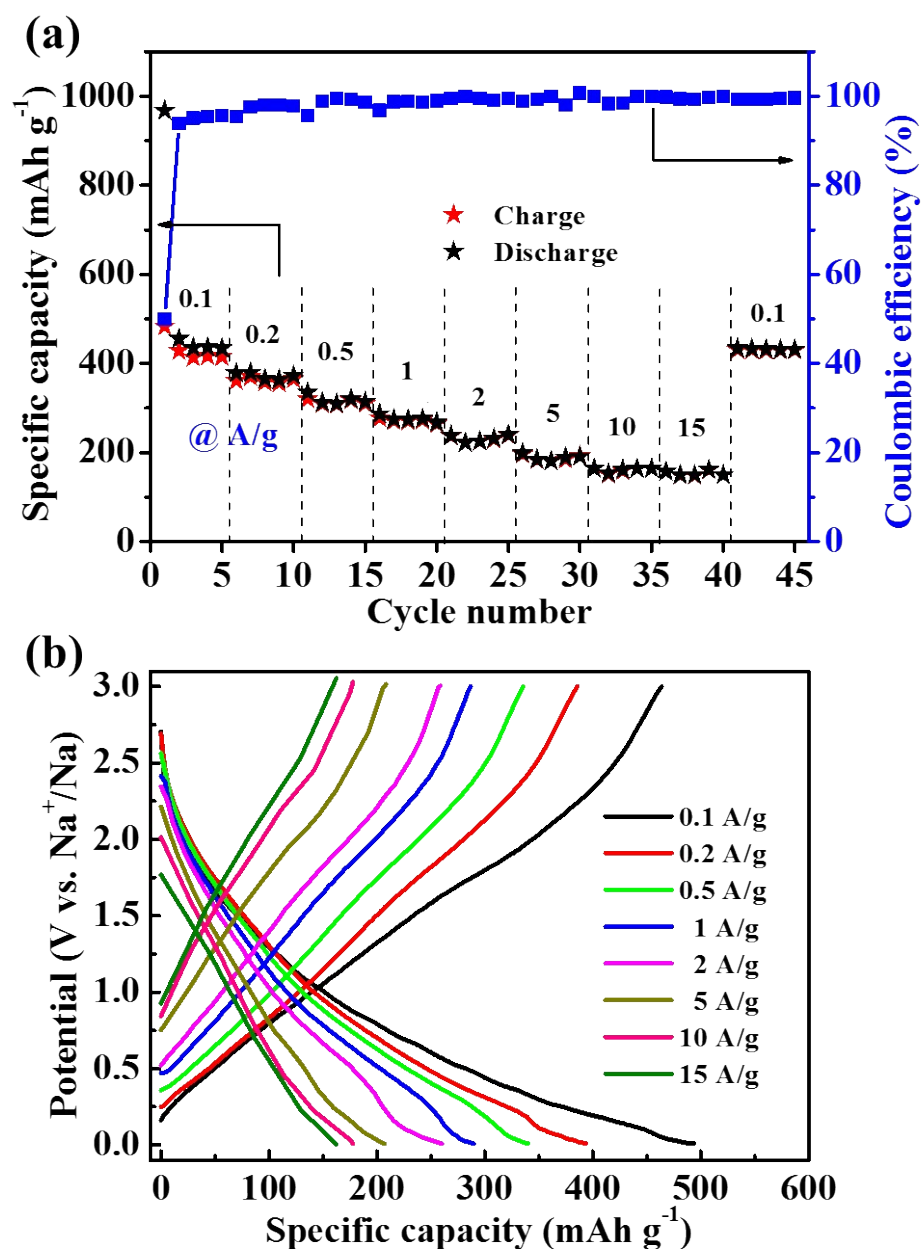


Fig. S8 (a) Rate performance and (b) GCD curves at different current densities of the $\text{MoS}_2@\text{BPC}$ electrode at the mass loading of $2 \text{ mg} \cdot \text{cm}^{-2}$.

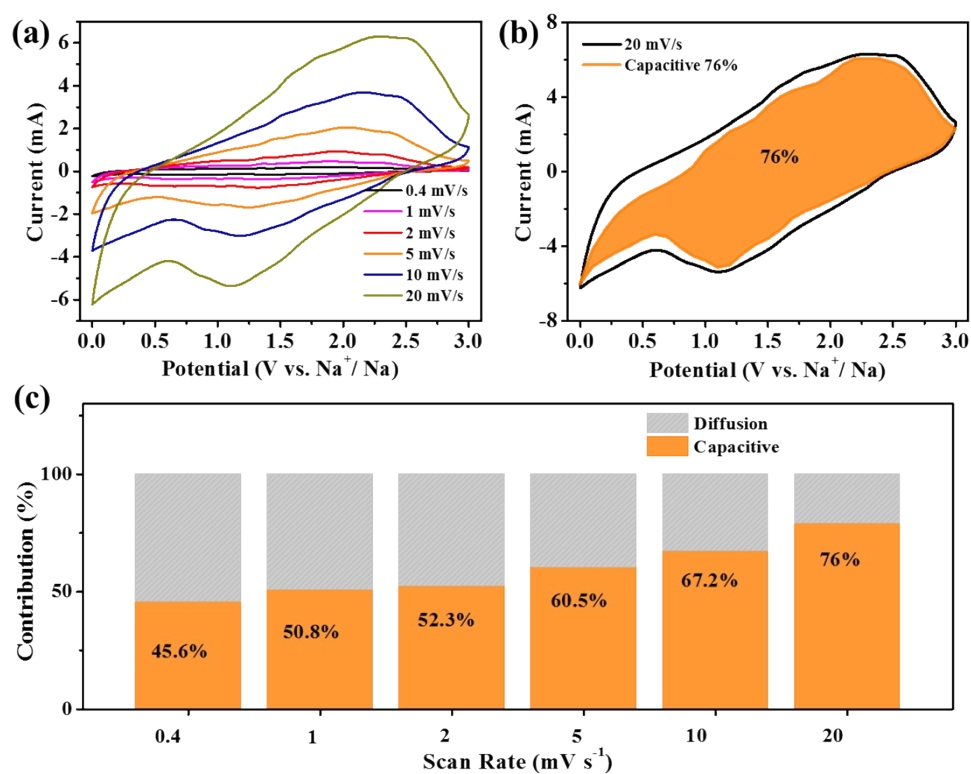


Fig. S9 (a) CV curves of the pure MoS₂ electrode at different scan rates. (b) Voltammetric response at a scan rate of 20 mV s⁻¹. The capacitive contribution to the total current is shown by the shaded region. (c) Normalized contribution ratio of capacitive capacities at different scan rates.

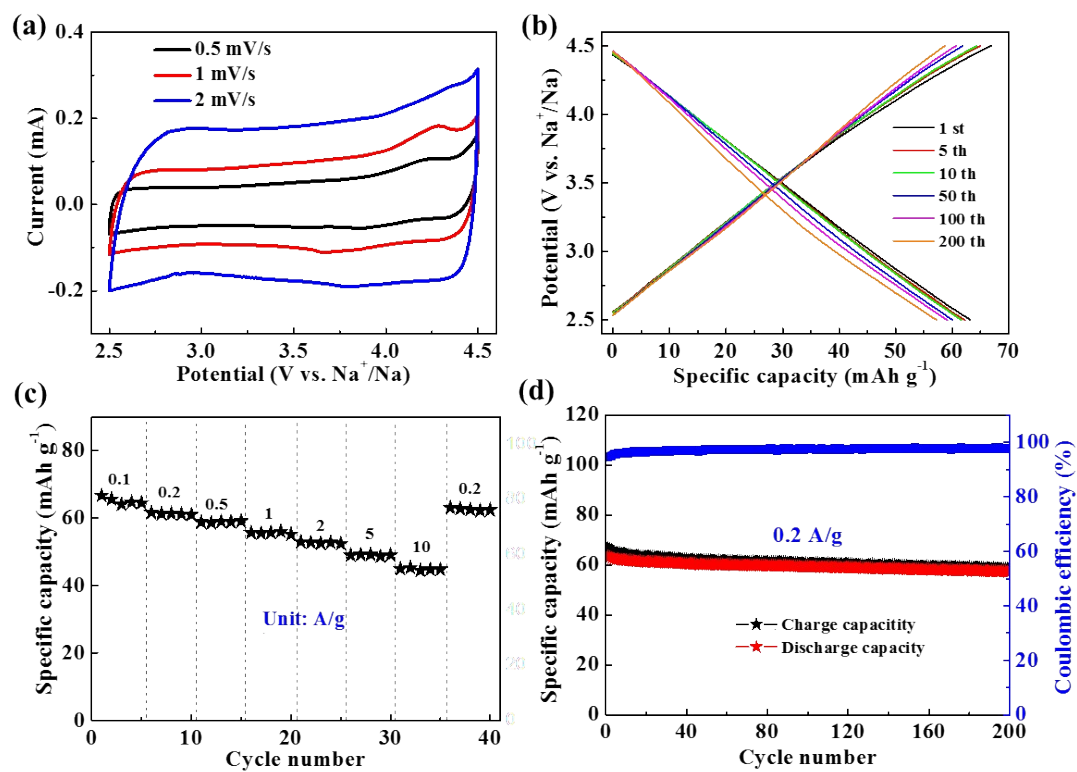


Fig. S10 (a) CV curves at different scan rates, (b) GCD curves, (c) Rate performance, and (d) Cycling performance at 0.2 A g^{-1} of BPC in the range of 2.5–4.5 V (vs Na/Na^+) as the cathode of NICs.

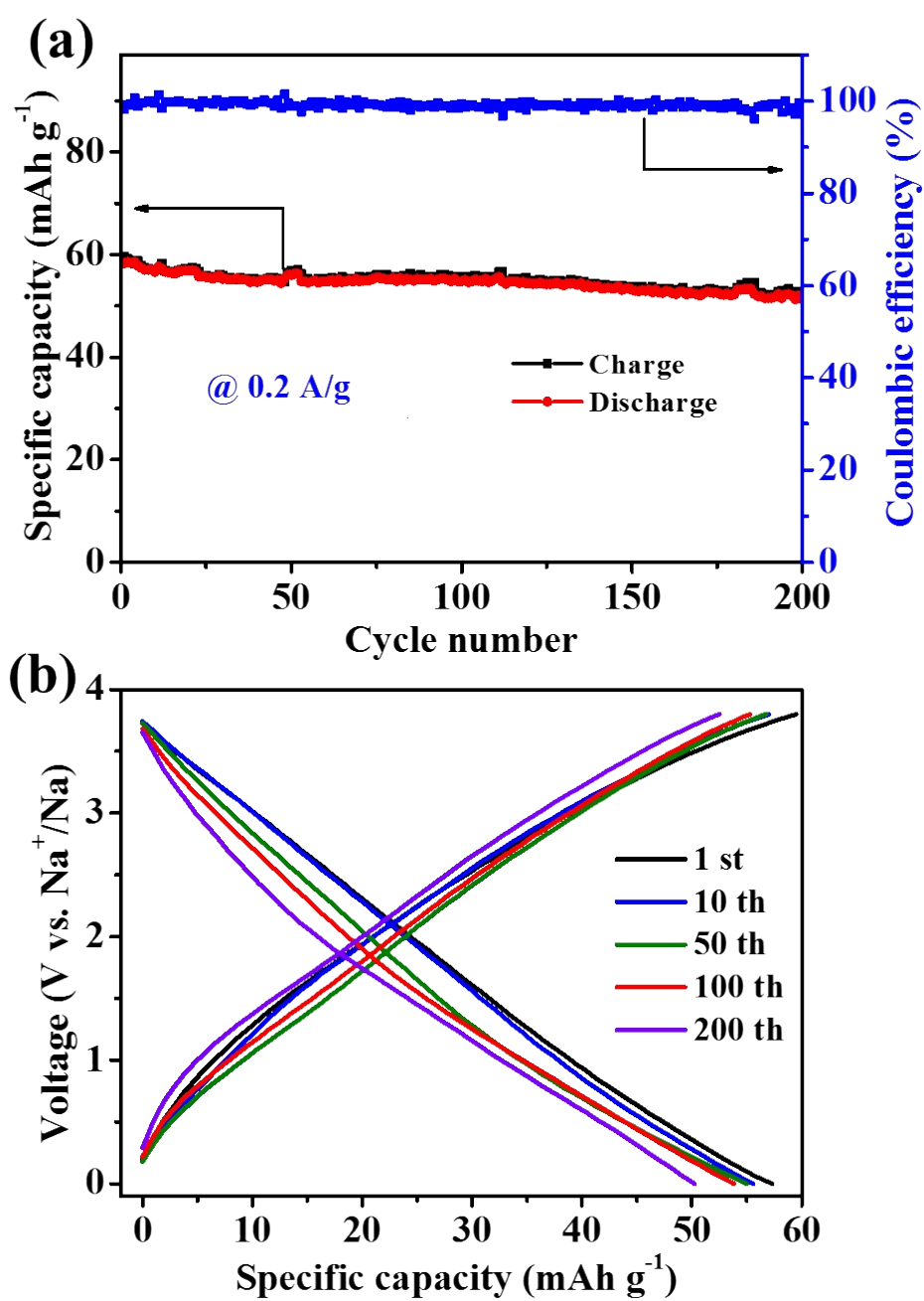


Fig. S11 (a) Cycling performances and (b) the corresponding GCD curves of the MoS₂@BPC//BPC NIC at 0.2 A g⁻¹.

Table S1 Comparison of cycle performance and rate performance for MoS₂@BPC anodes with the previous reports.

Materials	Voltage Range (V)	Cycle performance		Rate performance		Refs.
		Capacity (mAhg ⁻¹) /cycles	Current density (A·g ⁻¹)	Capacity (mAhg ⁻¹)	Current density (A·g ⁻¹)	
MoS ₂ nanoflowers	0.01-3	~250/300	0.2	200, 175	1, 10	1
MoS ₂ Nanosheets	0.01-3	386/100	0.04	530, 330,	0.04, 0.08,	2
		251/100	0.32	305, 251	0.16, 0.32	
3D MoS ₂ -Graphene Microspheres	0.001-3	480/50	0.2	427, 355,	1, 3,	3
		322/600	1.5	306, 273, 234	5, 7, 10	
MoS ₂ @RGO	0.01-3	420/600	0.1	450, 400, 280	0.1, 0.2, 2	4
		284/600	1			
MoS ₂ -RGO	0.005-2.5	305/50	0.1	305, 273, 245, 214	0.1, 0.25, 0.5, 1	5
MoS ₂ -Graphene	0.01-3	340/50	0.1	~390,	0.05,	6
		300/500	1	~350, ~300, 230	0.5, 2, 5	
3D MoS ₂ nanosheet/C NTs	0.005-2.5	504.6/100	0.05	504.6,	0.05,	7
		495.9/80	0.2	328.4	0.5	
MoS ₂ /SWNT	0.1-3	390/100	0.2	437, 404,	0.05, 0.2,	8
		~315/1000	0.5	341, 302, 268, 192	1, 5, 10, 20	
E-MoS ₂ /carbon fibers	0.01-3	241/700	1	298, 281,	0.05, 0.1,	9
		216/700	2	241, 222, 164, 138, 104	0.5, 1, 5, 10, 20	
Exfoliated MoS ₂ -C	0.01-2.5	390/100	0.1	~520, 400, 380, 350, 320, 300	0.05, 0.1, 0.2, 0.4, 1, 2	10
MoS ₂ /porous carbon	0.01-3	404/100	0.1	467, 406,	0.1, 0.2,	11
		280/300	1	338, 293, 183, 122	0.5, 1, 5, 10	
Vertically Aligned MoS ₂	0.01-3	286/100	0.08	348, 321, 271, 230, 205	0.04, 0.08, 0.32, 0.64, 1	12

@carbon						
MoS ₂ /C microspheres	0.05-3	~500/100	0.1	481, 406, 391, 339, 312, 244	0.1, 0.5, 1, 5, 10, 20	13
		390/2500	1			
MoS ₂ /C nanofibers	0.01-3	283.9/600	0.1	401, 370, 317, 283, 247, 148, 89	0.05, 0.1, 0.2, 0.5, 1, 3, 5	14
MoS ₂ /Porous Carbon	0.01-3	415/350	0.2	500, 345	0.1, 5	15
		340/550	1			
MoS ₂ @BPC	0.01-3	332.4/400	0.2	491.5, 420.6, 380.5, 345, 304.4, 251.5, 202.9, 179.8	0.1, 0.2, 0.5, 1, 2, 5, 10, 15	This work
		183.5/5000	2			

Table S2 Energy and power density comparison with the reports in the literature for hybrid NIC devices.

Positive electrode	Negative electrode	Voltage Window (V)	Energy density (Wh kg ⁻¹)	Corresponding Power density (W kg ⁻¹)	Refs.
PSC	Na ₂ Ti ₃ O ₇	0.5-3.5	111.2	800	16
			33.2	11200	
rGO	NaTi ₂ (PO ₄) ₃	0-2.7	334	53	17
			31	6700	
BAC	TiO ₂ @CNT@C	1-4	126	81.2	18
			37.9	12400	
GFs	Na ₂ Ti ₃ O ₇ /CT	1-3	55	200	19
			21.7	3000	
PDPC	TiO ₂ -RGO	1-4	94.7	247	20
			30.9	4093	
rGO-50	Nb ₂ O ₅ @C	1-4.3	76	80	21
			6	20800	
AC	NaTi ₂ (PO ₄) ₃	0.01-2.5	56	39	22
			31	4096	
AC	Ti(O,N)-MP-NWs	0.5-4	46	46	23
			10.9	11500	
PSC	Nb ₂ O ₅ nanosheets	1-3	43.2	160	24
			24	5760	
AC	Na-TNT	0-3	34	889	25
AC	N-TiO ₂	1-4	80.3	500	26
			24.6	12500	
PSC	NTO@CNT	0-3	58.5	300	27
			21.6	3000	
CFs	TiO ₂ /CFC	1.2-4.3	73.8	550	28
			20.5	13750	
NVP-AHD	nanoporous carbon	0.2-2.7	15	5424	29
AC	MWTOG	1-3.8	64.2	56.3	30
			25.8	1367	
BPC	BPC/MoS ₂	0-4	112.2	55	This work
			53.2	8333	

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